

HE (High-function Economy) Type [2-Channel (Form A) Type]

FEATURES

1. Compact 8-pin DIP size The device comes in a compact (W) 6.4×(L) 9.78×(H) 3.9 mm (W) .252×(L) .385×(H) .154 inch , 8-pin DIP size (through hole terminal type).

2. Applicable for 2 Form A use as well as two independent 1 Form A use

3. Controls low-level analog signals PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

4. High sensitivity, low ON resistance Can control a maximum 0.16 A (AQW254) load current with a 5 mA input current. Low ON resistance of 16 Ω (AQW254). Stable operation because there are no metallic contact parts.

5. Low-level off state leakage current

PhotoMOS RELAYS

The SSR has an off state leakage current of several miliamperes, whereas the PhotoMOS relay has only 100 pA even with the rated load voltage of 400 V (AQW254).

6. Low thermal electromotive force (Approx. 1 $\mu\text{V})$

TYPICAL APPLICATIONS

- High-speed inspection machines
- Data communication equipment
- Telephone equipment

TYPES Part No. Output rating* Packing quantity Through hole Surface-mount terminal terminal Туре Tape and reel packing style Load Load Tube packing style Tube Tape and reel Picked from the Picked from the current voltage 1/2/3/4-pin side 5/6/7/8-pin side 1 tube contains 40 pcs. 120 mA AC/DC 400 V AQW254 AQW254A AQW254AX AQW254AZ 1,000 pcs 1 batch contains 400 pcs.

*Indicate the peak AC and DC values.

Note: For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

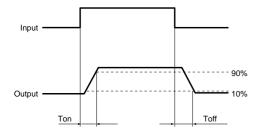
Item		Symbol	AQW254(A)	Remarks
Input	LED forward current	lF	50 mA	W.DL
	LED reverse voltage	VR	3 V	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
	Peak forward current	IFP	1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75 mW	
Output	Load voltage (peak AC)	VL	400 V	
	Continuous load current	0450	0.12 A (0.16 A)	A connection: Peak AC, DC (): in case of using only 1 channel
	Peak load current	Ipeak	0.36 A	A connection: 100 ms (1 shot), VL = DC
	Power dissipation	Pout	800 mW	
Total power dissipation		Ρτ	850 mW	
I/O isolation voltage		Viso	1,500 V AC	Between input and output/between contact sets
Temperature limits	Operating	Topr	−40°C to +85°C −40°F to +185°F	Non-condensing at low temperatures
	Storage	Tstg	-40°C to +100°C -40°F to +212°F	

AQW254

Item				Symbol	AQW254(A)	Condition
Input	LED operate current		Typical	Fon	0.9 mA	IL= Max.
			Maximum		3 mA	
	LED turn off current		Minimum	Foff	0.4 mA	l∟= Max.
			Typical		0.8 mA	
	LED dropout voltage		Typical	VF	1.14 V (1.25 V at I⊧ = 50 mA)	I⊧ = 5 mA
			Maximum	VF	1.5 V	
Output	On resistance		Typical	- Ron	12.4 Ω	I⊧ = 5 mA I∟ = Max. Within 1 s on time
			Maximum		16 Ω	
	Off state leakage current		Maximum	Leak	1 μΑ	I⊧ = 0 mA V∟ = Max.
Transfer characteristics	Switching speed	Turn on time*	Typical	Ton	0.8 ms	IF = 5 mA IL = Max. IF = 5 mA IL = Max.
			Maximum		2 ms	
		Turn off time*	Typical	Toff	0.05 ms	
			Maximum		0.2 ms	
	I/O capacitance		Typical	Ciso	0.8 pF	f = 1 MHz Vв = 0
			Maximum		1.5 pF	
	Initial I/O isolation resistance Minimum		Minimum	Riso	1,000 MΩ	500 V DC

Note: Recommendable LED forward current $I_F = 5$ mA.

*Turn on/Turn off time



For type of connection, see page 32.

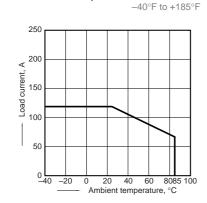
■ For Dimensions, see Page 27.

■ For Schematic and Wiring Diagrams, see Page 32.

■ For Cautions for Use, see Page 36.

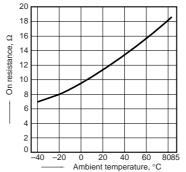
REFERENCE DATA

1. Load current vs. ambient temperature characteristics Allowable ambient temperature: -40°C to +85°C



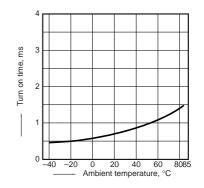
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



3. Turn on time vs. ambient temperature characteristics

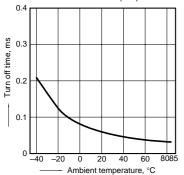
LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



AQW254

4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



7. LED dropout voltage vs. ambient tempera-

ture characteristics

1.4

1.2

1.1

1.0

0

40 -20

>

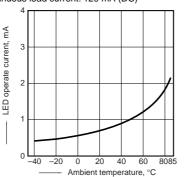
dropout voltage,

ĒD

LED current: 5 to 50 mA

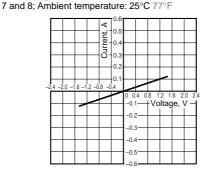
5. LED operate current vs. ambient temperature characteristics

Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



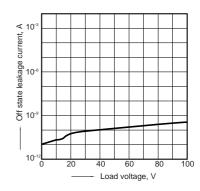
8. Voltage vs. current characteristics of output

at MOS portion Measured portion: between terminals 5 and 6,



6. LED turn off current vs. ambient temperature characteristics

9. Off state leakage current Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



10. LED forward current vs. turn on time characteristics

20 40

Ambient temperature, °C

0

30mA

20mA

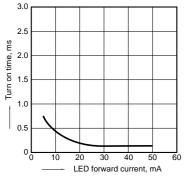
10mA

nA

8085

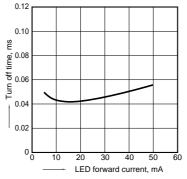
60

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: $25^{\circ}C$ $77^{\circ}F$



11. LED forward current vs. turn off time characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: $25^{\circ}C$ $77^{\circ}F$



12. Applied voltage vs. output capacitance characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz; Ambient temperature: $25^{\circ}C$ $77^{\circ}F$

